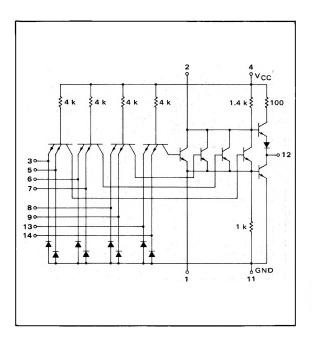
EXPANDABLE 4-WIDE 2-INPUT "AND-OR-INVERT" GATE

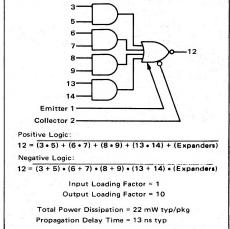
MCBC5400/MCB5400F series

MCBC5453* MCB5453F*



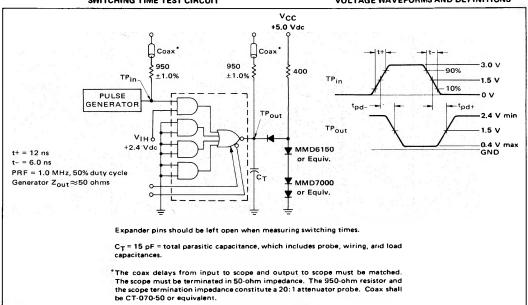


This device consists of four 2-input AND gates ORed together and inverted. Up to four MCB5400 expander gates may be ORed with the device at the expander points. Beam lead sealed junction technology is used to manufacture these devices. They are particularly useful in highly reliable systems using hybrid beam lead assembly techniques or standard flat package assembly techniques.



SWITCHING TIME TEST CIRCUIT

VOLTAGE WAVEFORMS AND DEFINITIONS



^{*}F suffix = 1/4" x 1/4" ceramic package (Case 651). MCBC-prefixed devices are unencapsulated. Beam numbers are the same as the pin numbers for flat-packaged devices. See General Information section for package and chip detail.

FIGURE 1 - IEX TEST CIRCUIT

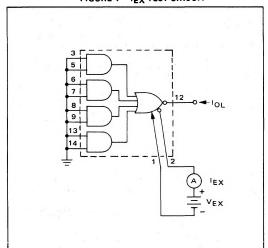


FIGURE 2 - VBE TEST CIRCUIT

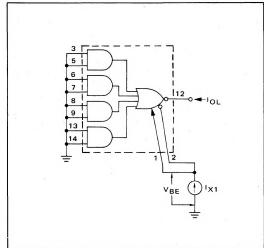
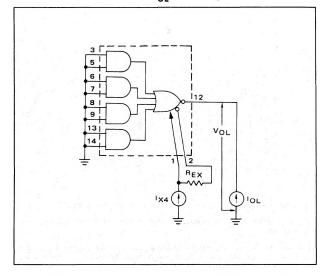


FIGURE 3 - VOL TEST CIRCUIT



a manner.

Pin MCBCs453/MCB545F 16	w 31		r 引	ا م	12							TEST	CURREN	TEST CURRENT/VOLTAGE VALUES (All Temperatures)	GE VAL	UES (A	Tempe	ratures						<u> </u>	
Emitter 1 Collector 2 Collector 2 Collector 2 Collector 3 Collector 4 Collector 4 Collector 5 Collector 7 Collect	***************************************		7						mA	- 1		F	Ohms					^	ofts						
Collector 2 Collector 2 Collector 2 Collector 2 Collector 2 Collector 2 Collector 3 Collector 4 Collector 4 Collector 5 Collector 5 Collector 6 Collector 6 Collector 6 Collector 7	1. Emitter	1		$\overline{1}$			ام	-N	-ix	l _{x2}	l _{x3}	+	-	V _{EX}	V		V.HH	V	1	, *	V.40	V _{cc}	Vcc1	CG	
Part		2					16	-0.4	0.41	0.27	_	0,3	138	0.4	0.4		5.5			2.0		5.0		5.5	
The contract of the contract	_		Pin		Test Lin S453/M	iits CB5453F						TEST CU	RRENT/V	OLTAGE	APPLIE	TO PII	NS LIST	ED BELO							
1	Characteristic	Symbol	_	2	Max Max	Unit	101	-NO	-ix	l _{x2}	-x	-	-	VEX®	_	>	V IHH	VRI	V _{R2}	>	٧ بيه	Vcc	Vccı	CCH	Gnd
Fig. 3 1.0 m/dc 1.2 1.0 m/dc 1.2 1.2 1.3 1.0 m/dc 1.2 1.3 1.4 1.3 1.4 1.4 1.4 1.5	Input Forward Current	4	m	i	-1.6	mAde	1	4	Þ.	7		i		i.				un.	1,0		4	- 1		4	II.
Fig. 3 1.0 Indee 12 1.2 1.2 Indee 12 1.2 Indee 12 Indee 13 Indee	Leakage Current	IR1	m	1	40	µAdc.	- 1	Q.	1	ī	11	1	7-	-1-	1	69			1	1	4	91	7		3,6,7,8,9,
Voltage Value Voltage Value		¹ R2	69	è	1.0	mAde	Ţ	1	i	1	1	1	1	i-	i.	10	89	0	4	10	1		in.		3,6,7,8,9,
Voltage Voltage 1 (2) 1.0 Vdc 12 1.2 <t< td=""><td>Expander Input Current</td><td>¹EX</td><td>2 ①</td><td></td><td>-2.9</td><td></td><td>12</td><td></td><td>1-</td><td>5</td><td></td><td></td><td></td><td>1,2</td><td>1</td><td>4</td><td>1</td><td>1</td><td>1</td><td>1</td><td></td><td>e e i</td><td>4</td><td>1</td><td>3,5,6,7,8,9,</td></t<>	Expander Input Current	¹ EX	2 ①		-2.9		12		1-	5				1,2	1	4	1	1	1	1		e e i	4	1	3,5,6,7,8,9,
Voltage Voltage 12 (3) 0.4 Vdc 12 1 2 4 4 Strout Current 12 (3) 1.2 2.4 Vdc 1.2 1.2 5.68 4 4 Strout Current 1/5C 1.2 2.4 Vdc 1.2 1.2 5.68 4 1 4 1 4 1 4 1 2 1 4 </td <td>Base-Emitter Voltage</td> <td>VBE</td> <td>1 3</td> <td>11</td> <td>1.0</td> <td>Vdc</td> <td>12</td> <td>2</td> <td>1,2</td> <td></td> <td>,</td> <td></td> <td>4</td> <td>-</td> <td>3,5,6,7,8,9,</td>	Base-Emitter Voltage	VBE	1 3	11	1.0	Vdc	12	2	1,2												,		4	-	3,5,6,7,8,9,
12	Output Output Voltage	NOL.	12	(0)	0.4	Vdc	12		i	7	-(-	1	-7	-	90		ν.	.30		in,	-		4	1	6,7,8,9,
VoH 12 2.4 - Vdc - 12 12 - Vdc - 12 - Vdc - 12 - Vdc - 13 - 1 2 - Vdc - S,6.8, 4 - S,6.8, 4 - S,6.8, 4 - S,6.8, 4 - S,6.8, 6.7 8 - S,6.8, 7 8 - S,6.8, 7 8 - S,6.8, 7 8 - S,7.8,			12③		9.4	Vde	12		i			1	64				1	•		•			*		3,5,6,7,8,9,
12 2.4 1.4 1.5		ио ^л	12	2.4	4	Vdc		12		3		4	-	9	4	-		3,7,	r	y	5,6,8,		4	T.	11
1 1 1 1 1 1 1 1 1 1			12	2.4	7	Vdc		12	ď	1.	21	•			•								*		3,5,6,7,8,9,
IppH 4 9.5 mAdc 9.5 mAdc 4 4 3,56,7,8 4 4 IppL 4 8.0 mAdc Pulse	Short-Circuit Current	JS ₁	12	-20	-55	mAdc	,												,	1					,5,6,7,8,9,11,
TppL 4 8:0 mAdc Pulse tpd- 3,12 13** ns 3 12 tpd+ 3,12 22** ns 3 12 4	Power Requirements Power Supply Drain	HOd	4	,	6	mAde				•	•		,	,	,	,			3,5,6,7,8,		4			41	п
thd. 3,12 - 15** ns 3 12 5 5 4		TGd_{I}	4	4	8.0	mAdc					-	-					-		,	1				-	3,5,6,7,8,9,
tot. 3,12 . 15** ns 3 12	Switching Parameters						Pulse	Pulse				_													
tpd+ 3,12 - 22** ns 3 12 5 5 4 4	Turn-On Delay	Ŗ	3,12	1	15**	ns	67	12	1	i.	1	I.	1	1	5	v				1		4			6,7,8,9,
	Turn-Off Delay	t pd+	3,12	C	22**	su	m	12	-£	1	Ŀ	1		1	r	un.	,	¥.	9	-(.		4		-	6,7,8,9,

** Tested only at 25°C.

Ü See Figure 1.

② See Figure 2.